

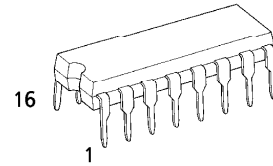
TC74HC592AP, TC74HC592AF

8-BIT BINARY COUNTER WITH INPUT REGISTER

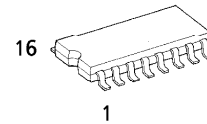
The TC74HC592A is high speed CMOS 8-BIT REGISTER COUNTER fabricated with silicon gate C²MOS technology. It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation. The internal counter counts at positive edge of Counter Clock (CCK) when Counter Clock Enable ($\overline{\text{CCKEN}}$) is held "L" level. If Counter clear ($\overline{\text{CCLR}}$) is held "L", the internal counter is cleared asynchronously to clock. Input A~H are loaded to register at positive edge of Register Clock (RCK), and the register outputs are loaded to Counter when Counter Load ($\overline{\text{CLOAD}}$) is held "L" level. All inputs are equipped with protection circuits against static discharge or transient excess voltage.

FEATURES:

- High Speed..... $f_{\text{MAX}} = 35\text{MHz}(\text{typ.})$
at $V_{\text{CC}} = 5\text{V}$
- Low Power Dissipation..... $I_{\text{CC}} = 4\mu\text{A}(\text{Max.})$ at $T_a = 25^\circ\text{C}$
- High Noise Immunity..... $V_{\text{NIH}} = V_{\text{NIL}} = 28\% V_{\text{CC}}(\text{Min.})$
- Output Drive Capability.....10 LSTTL Loads
For QA~QH
- Symmetrical Output Impedance... $|I_{\text{OH}}| = I_{\text{OL}} = 4\text{mA}(\text{Min.})$
- Balanced Propagation Delays..... $t_{\text{PLH}} \approx t_{\text{PHL}}$
- Wide Operating Voltage Range.... $V_{\text{CC}}(\text{opr.}) = 2\text{V} \sim 6\text{V}$
- Pin and Function Compatible with 74LS592

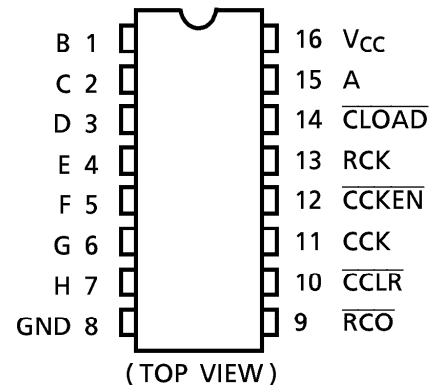


P (DIP16-P-300-2.54A)
Weight : 1.00g (Typ.)



F (SOP16-P-300-1.27)
Weight : 0.18g (Typ.)

PIN ASSIGNMENT



TRUTH TABLE

INPUT					FUNCTION
RCK	$\overline{\text{CLOAD}}$	$\overline{\text{CCLR}}$	$\overline{\text{CCKEN}}$	CCK	
X	L	H	X	X	REGISTER DATA IS LOADED INTO COUNTER
X	H	L	X	X	COUNTER CLEAR
	H	H	X	X	THE DATA OF A THRU H INPUTS IS STORED INTO REGISTER
	H	H	X	X	REGISTER STATE IS NOT CHANGED
X	H	H	L		COUNTER ADVANCES THE COUNT
X	H	H	L		NO COUNT
X	H	H	H	X	NO COUNT

X : Don't care

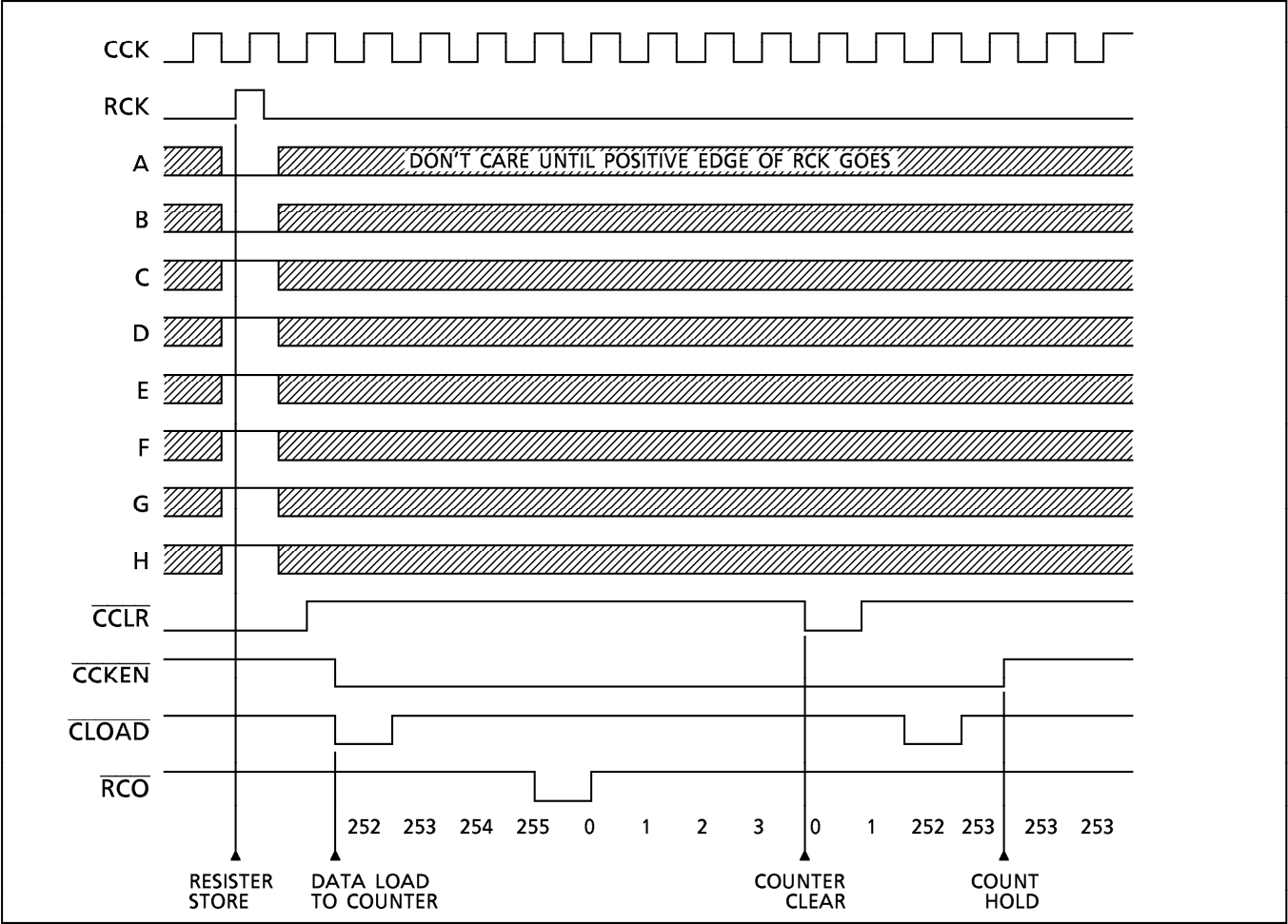
$$\overline{\text{RCO}} = \text{QA}' \cdot \text{QB}' \cdot \text{QC}' \cdot \text{QD}' \cdot \text{QE}' \cdot \text{QF}' \cdot \text{QG}' \cdot \text{QH}'$$

(QA'~QH' : Internal outputs of the counter)

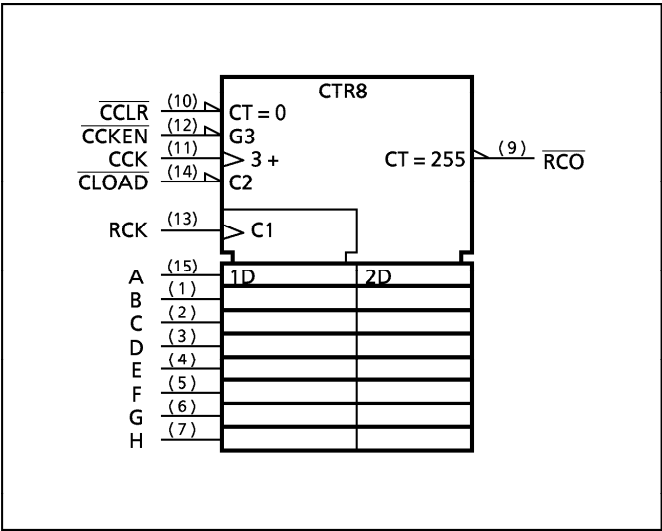
961001EBA2

● TOSHIBA is continually working to improve the quality and the reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to observe standards of safety, and to avoid situations in which a malfunction or failure of a TOSHIBA product could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent products specifications. Also, please keep in mind the precautions and conditions set forth in the TOSHIBA Semiconductor Reliability Handbook.

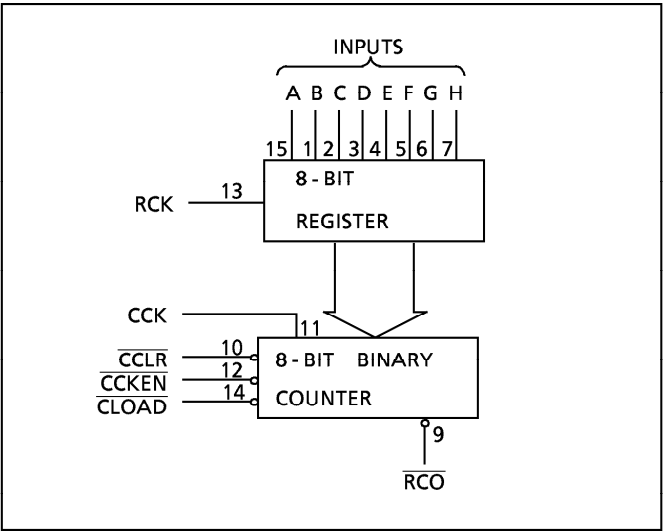
TIMING CHART



IEC LOGIC CHART



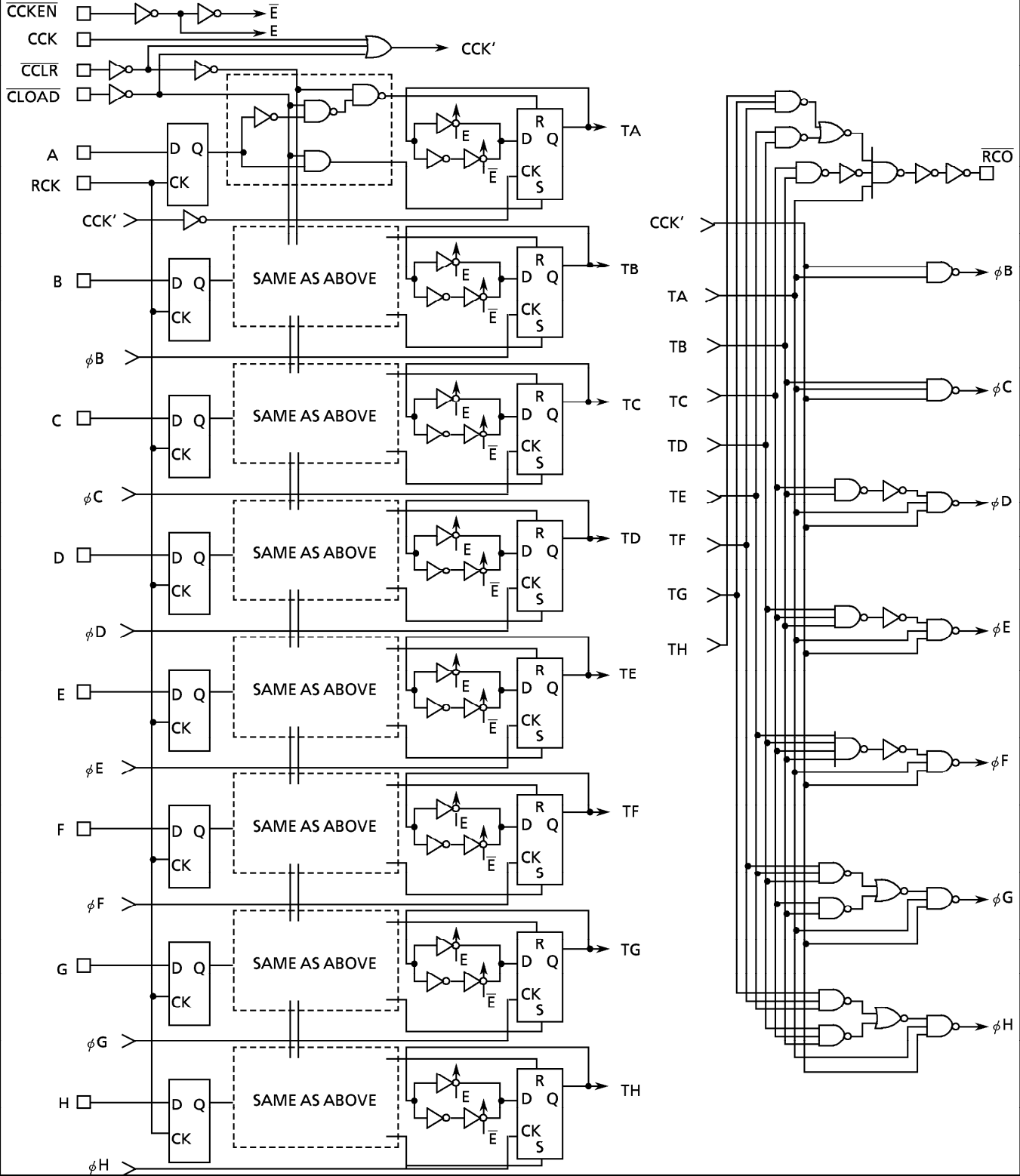
BLOCK DIAGRAM



961001EBA2'

● The products described in this document are subject to foreign exchange and foreign trade control laws.
● The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.
● The information contained herein is subject to change without notice.

SYSTEM DIAGRAM



ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	V_{CC}	$-0.5 \sim 7$	V
DC Input Voltage	V_{IN}	$-0.5 \sim V_{CC} + 0.5$	V
DC Output Voltage	V_{OUT}	$-0.5 \sim V_{CC} + 0.5$	V
Input Diode Current	I_{IK}	± 20	mA
Output Diode Current	I_{OK}	± 20	mA
DC Output Current	I_{OUT}	± 25	mA
DC V_{CC} /Ground Current	I_{CC}	± 50	mA
Power Dissipation	P_D	500 (DIP)* / 180 (SOP)	mW
Storage Temperature	T_{stg}	$-65 \sim 150$	°C

*500mW in the range of $T_a = -40^\circ\text{C} \sim 65^\circ\text{C}$. From $T_a = 65^\circ\text{C}$ to 85°C a derating factor of $-10\text{mW}/^\circ\text{C}$ shall be applied until 300mW.

RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	V_{CC}	$2 \sim 6$	V
Input Voltage	V_{IN}	$0 \sim V_{CC}$	V
Output Voltage	V_{OUT}	$0 \sim V_{CC}$	V
Operating Temperature	T_{opr}	$-40 \sim 85$	°C
Input Rise and Fall Time	t_r, t_f	$0 \sim 1000 (V_{CC} = 2.0\text{V})$ $0 \sim 500 (V_{CC} = 4.5\text{V})$ $0 \sim 400 (V_{CC} = 6.0\text{V})$	ns

DC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITION	V_{CC} (V)	$T_a = 25^\circ\text{C}$			$T_a = -40 \sim 85^\circ\text{C}$		UNIT
				MIN.	TYP.	MAX.	MIN.	MAX.	
High - Level Input Voltage	V_{IH}		2.0 4.5 6.0	1.50 3.15 4.20	— — —	— — —	1.50 3.15 4.20	— — —	V
Low - Level Input Voltage	V_{IL}		2.0 4.5 6.0	— — —	— — —	0.50 1.35 1.80	— — —	0.50 1.35 1.80	V
High - Level Output Voltage	V_{OH}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	$I_{OH} = -20\mu\text{A}$	2.0 4.5 6.0	1.9 4.4 5.9	2.0 4.5 6.0	— — —	1.9 4.4 5.9	V
			$I_{OH} = -4 \text{ mA}$ $I_{OH} = -5.2 \text{ mA}$	4.5 6.0	4.18 5.68	4.31 5.80	— —	4.13 5.63	
Low - Level Output Voltage	V_{OL}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	$I_{OL} = 20\mu\text{A}$	2.0 4.5 6.0	— — —	0.0 0.0 0.0	— — —	0.1 0.1 0.1	V
			$I_{OL} = 4 \text{ mA}$ $I_{OL} = 5.2 \text{ mA}$	4.5 6.0	— —	0.17 0.18	— —	0.33 0.33	
Input Leakage Current	I_{IN}	$V_{IN} = V_{CC} \text{ or GND}$	6.0	—	—	± 0.1	—	± 1.0	μA
Quiescent Supply Current	I_{CC}	$V_{IN} = V_{CC} \text{ or GND}$	6.0	—	—	4.0	—	40.0	

TIMING REQUIREMENTS (Input $t_r = t_f = 6\text{ns}$)

PARAMETER	SYMBOL	TEST CONDITION	Ta = 25°C			Ta = -40~85°C	UNIT
			V _{CC} (V)	TYP.	LIMIT	LIMIT	
Minimum Pulse Width (CCK, RCK)	$t_{W(H)}$ $t_{W(L)}$		2.0	—	75	95	ns
			4.5	—	15	19	
			6.0	—	13	16	
Minimum Pulse Width (CCLR)	$t_{W(L)}$		2.0	—	100	125	
			4.5	—	20	25	
			6.0	—	16	21	
Minimum Pulse Width (CLOAD)	$t_{W(L)}$		2.0	—	175	220	
			4.5	—	35	44	
			6.0	—	30	37	
Minimum Set-up Time (CCKEN—CCK)	t_s		2.0	—	75	95	
			4.5	—	15	19	
			6.0	—	13	16	
Minimum Set-up Time (RCK—CLOAD)	t_s		2.0	—	150	190	
			4.5	—	30	38	
			6.0	—	26	32	
Minimum Set-up Time (A~H—RCK)	t_s		2.0	—	100	125	
			4.5	—	20	25	
			6.0	—	17	21	
Minimum Hold Time	t_h		2.0	—	5	5	
			4.5	—	5	5	
			6.0	—	5	5	
Minimum Removal Time (CCLR)	t_{rem}		2.0	—	75	95	
			4.5	—	15	19	
			6.0	—	13	16	
Minimum Removal Time (CLOAD)	t_{rem}		2.0	—	75	95	
			4.5	—	15	19	
			6.0	—	13	16	
Clock Frequency	f		2.0	—	4	3.5	MHz
			4.5	—	22	18	
			6.0	—	26	21	

AC ELECTRICAL CHARACTERISTICS ($C_L = 15\text{pF}$, $V_{CC} = 5\text{V}$, $T_a = 25^\circ\text{C}$, Input $t_r = t_f = 6\text{ns}$)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Output Transition Time	t_{TLH} t_{THL}		—	6	12	ns
Propagation Delay Time ($\text{CCK} - \overline{\text{RCO}}$)	t_{pLH} t_{pHL}		—	25	38	
Propagation Delay Time ($\text{RCK} - \overline{\text{RCO}}$)	t_{pLH} t_{pHL}		—	39	60	
Propagation Delay Time ($\text{CCLR} - \overline{\text{RCO}}$)	t_{pLH}		—	24	36	
Propagation Delay Time ($\text{CLOAD} - \overline{\text{RCO}}$)	t_{pLH} t_{pHL}		—	35	53	
Maximum Clock Frequency	f_{MAX}		25	35	—	MHz

AC ELECTRICAL CHARACTERISTICS ($C_L = 50\text{pF}$, Input $t_r = t_f = 6\text{ns}$)

PARAMETER	SYMBOL	TEST CONDITION	V _{CC} (V)	Ta = 25°C			Ta = −40~85°C		UNIT
				MIN.	TYP.	MAX.	MIN.	MAX.	
Output Transition Time	t _{TLH} t _{THL}		2.0	—	30	75	—	95	ns
			4.5	—	8	15	—	19	
			6.0	—	7	13	—	16	
Propagation Delay Time (CCK—RCO)	t _{pLH} t _{pHL}		2.0	—	94	220	—	275	
			4.5	—	29	44	—	55	
			6.0	—	24	37	—	47	
Propagation Delay Time (RCK—RCO)	t _{pLH} t _{pHL}		2.0	—	160	340	—	425	
			4.5	—	45	68	—	85	
			6.0	—	34	58	—	73	
Propagation Delay Time (CCLR—RCO)	t _{pHL}		2.0	—	89	215	—	270	
			4.5	—	28	43	—	54	
			6.0	—	22	37	—	46	
Propagation Delay Time (CLOAD—RCO)	t _{pLH} t _{pHL}		2.0	—	140	300	—	375	
			4.5	—	40	60	—	75	
			6.0	—	30	51	—	64	
Maximum Clock Frequency	f _{MAX}		2.0	4	20	—	3.5	—	MHz
			4.5	22	33	—	18	—	
			6.0	26	49	—	21	—	
Input Capacitance	C _{IN}			—	5	10	—	10	pF
Power Dissipation Capacitance	C _{PD} (1)			—	31	—	—	—	

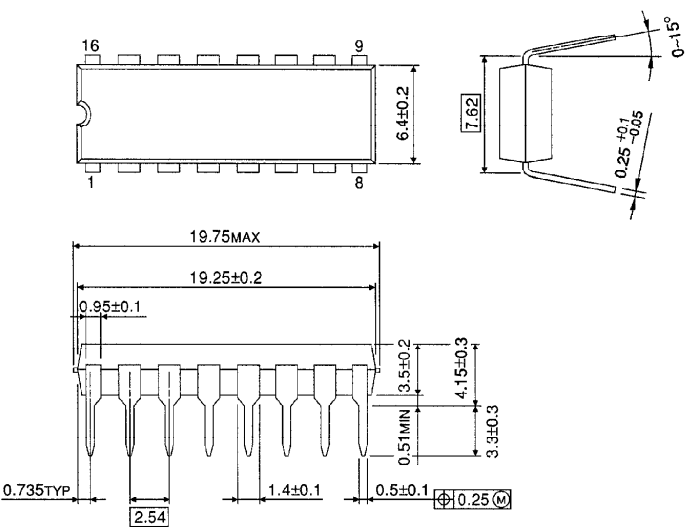
Note (1) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation :

$$I_{\text{CC}}(\text{opr}) = C_{\text{PD}} \cdot V_{\text{CC}} \cdot f_{\text{IN}} + I_{\text{CC}}$$

DIP 16PIN OUTLINE DRAWING (DIP16-P-300-2.54A)

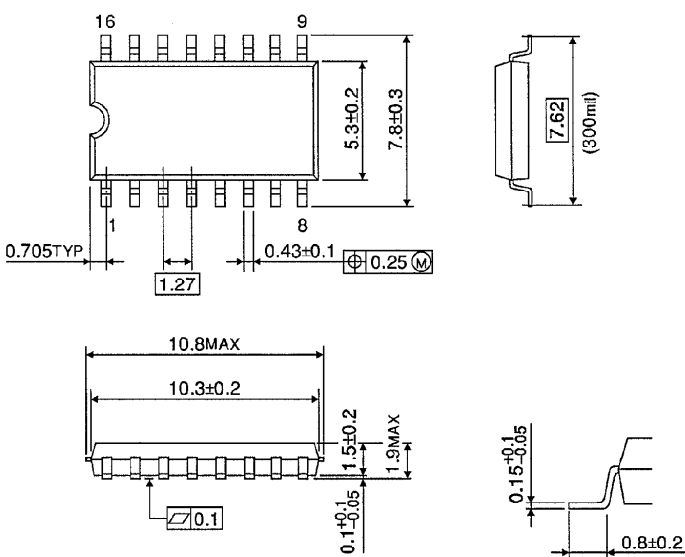
Unit in mm



Weight : 1.00g (Typ.)

SOP 16PIN (200mil BODY) OUTLINE DRAWING (SOP16-P-300-1.27)

Unit in mm



Weight : 0.18g (Typ.)